

Effect of Parametric Uncertainties on the Performance of a Piezoelectric Energy Harvesting Device

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The use of piezoelectric materials for the development of electromechanical devices for the harvesting or scavenging of ambient vibrations has been extensively studied over the last decade. The energy conversion from mechanical (vibratory) to electrical energy is provided by the electromechanical coupling between mechanical strains/stresses and electric charges/voltages in the piezoelectric material. The majority of the studies found in the open literature present a tip-mass cantilever piezoelectric device tuned on the operating frequency. Although recent results show that these devices can be quite effective for harvesting small amounts of electrical energy, little has been published on the robustness of these devices or on the effect of parametric uncertainties on the energy harvested. This work focuses on a cantilever plate with bonded piezoelectric patches and a tip-mass serving as an energy harvesting device. The rectifier and storage electric circuit was replaced by a resistive circuit (R). In addition, an alternative to improve the harvesting performance by adding an inductance in series to the harvesting circuit, thus leading to a resonant circuit (RL), is considered. A coupled finite element model leading to mechanical (displacements) and electrical (charges at electrodes) degrees of freedom is considered. An analysis of the effect of parametric uncertainties of the device on the electric output is performed. Piezoelectric and dielectric constants of the piezoelectric active layers and electric circuit equivalent inductance are considered as stochastic parameters. Mean and confidence intervals of the electric output are evaluated.

Keywords: energy harvesting, energy scavenging, uncertainties, piezoelectric materials, resonant shunt circuits

Introduction

The use of piezoelectric materials for the development of energy harvesting devices has been largely studied over the last decade (Sodano, Inman and Park, 2004). The motivation for the use of such materials as energy harvesting devices is based on their vast employment as distributed sensors and actuators due to their large electromechanical coupling coefficient. Piezoelectric materials can be found in the form of thin monolithic patches or fiber reinforced composites which can be easily integrated into flexible structures without significant mass increase (Sodano, Lloyd and Inman, 2006; Trindade and Benjeddou, 2012). Thus, the conversion of vibratory energy into electrical energy through the electromechanical coupling of piezoelectric materials could be useful in several applications (Roundy, 2005; Beeby, Tudor and White, 2006).

Most of the research found in the open literature explores the use of electromechanical resonant devices tuned to the operational resonance frequency of the host structure or machine in order to maximize the electrical energy harvested or generated. The vast majority of the considered devices are based on a cantilever beam with tip mass whose properties are tuned accordingly so that the device resonance frequency matches the operating frequency. The electrical energy is generated by one or more piezoelectric patches bonded to a cantilever substrate. Through their electrodes, the piezoelectric patches can convert part of their strain energy into useful electrical energy. This induced electric current should be directed to a proper electric circuit responsible for signal rectification and energy storage (Ottman et al., 2002; Guyomar et al., 2005; Guan and Liao, 2007).

The performance of these resonant devices for energy harvesting is greatly dependent on the adequate tuning between resonant and operation frequencies. Any mismatch due to variability of the device properties or operation frequency may lead to large performance losses (Adhikari, Friswell and Inman, 2009). Therefore, the

device's resonant frequency should be very well estimated or known. Consequently, the predictive model considered to design the device may be extremely important. Although the majority of the studies found in the literature use one degree of freedom models to represent the cantilever beam with tip mass, this simplification may lead to an incorrect prediction of the resonance frequency of the device and, therefore, to an inadequate frequency tuning (Erturk and Inman, 2008).

Moreover, few studies have attempted to analyze the effect of parametric uncertainties on the energy harvesting performance. Ali, Friswell and Adhikari (2010) studied the effect of uncertainties of an energy harvesting device resonance frequency and damping factor on its performance. On the other hand, uncertainties of electric shunt circuits on piezoelectric shunt damping for passive and active-passive structural vibration control have been studied recently (Andreas and Porfiri, 2007; Santos and Trindade, 2011).

Therefore, the main objective of this study is to perform an analysis of the effect of parametric uncertainties of the piezoelectric device on the harvested energy. A cantilever plate with bonded piezoelectric patches and a tip-mass serves as the energy harvesting device. Piezoelectric and dielectric constants of the piezoelectric active layers and electric circuit equivalent inductance are considered as stochastic parameters. Mean and confidence intervals of the harvested energy output are evaluated. In addition, an assessment of energy harvesting performance quantification metrics was performed and an alternative analysis using the electric current per unit velocity is proposed.

Problem Description

A piezoelectric energy harvesting device can be designed using a cantilever plate partially covered with piezoelectric layers or patches and a tip mass to adjust the resonance frequency of the device. This was done here using an aluminium plate with dimensions $60 \times 25 \times 1 \text{ mm}^3$ on the surfaces of which two PZT-5A piezoceramic

patches with dimensions $55 \times 25 \times 0.25 \text{ mm}^3$ are bonded, as shown in Fig. 1. The aluminium plate is clamped at one of its smaller sides to a moving base and a seismic mass is attached to the opposite side. The base is free to move in the transversal direction to represent the base excitation of the device. The material properties are: i) Aluminum – Young's modulus 70 GPa, Poisson's ratio 0.33, mass density 2700 kg/m^3 ; and ii) PZT-5A – $\bar{c}_{11}^D = \bar{c}_{22}^D = 96.39 \text{ GPa}$, $\bar{c}_{12}^D = 51.22 \text{ GPa}$, $\bar{c}_{44}^D = \bar{c}_{55}^D = 39.63 \text{ GPa}$, $\bar{c}_{66}^D = 22.57 \text{ GPa}$, $\bar{h}_{31} = \bar{h}_{32} = -1.677 \cdot 10^9 \text{ N C}^{-1}$, $\bar{\beta}_{33}^\varepsilon = 104.5 \cdot 10^6 \text{ m F}^{-1}$, $\rho^{pzt} = 7750 \text{ kg m}^{-3}$. The energy harvesting electric circuit is represented here by a simple electric load with resistance R_c . The energy dissipated in the electric resistance can be thought then as an upper limit to the potentially harvested energy. In addition, an electric inductance L_c may be connected in series to the harvesting circuit. If properly adjusted, the inductance may induce a resonant behavior in the circuit, increasing the electric current and, thus, the harvested energy.

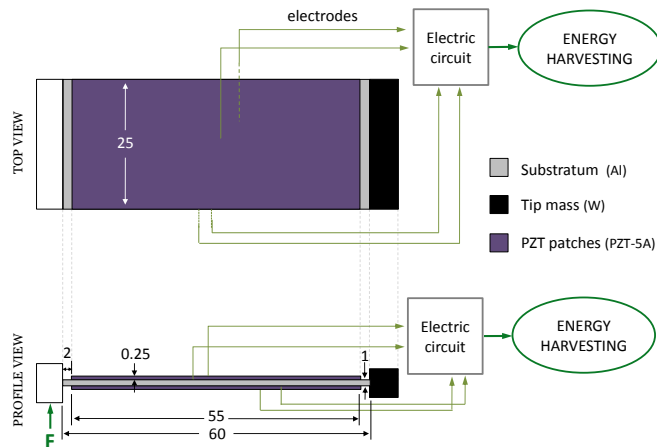


Figure 1. Cantilever plate with two PZT transducers patches connected to an electric circuit for energy harvesting.

To maximize the energy harvesting performance, it is normally desirable to maximize the strains in the piezoelectric materials such that more vibratory energy is available to be converted to electric energy by the piezoelectric material. This can be done by maximizing the vibration amplitude of the cantilever plate for a given excitation which, in turn, suggests to match the operating (excitation) frequency with the device natural frequency. In this work, the operating frequency is assumed to be 100 Hz. A first estimate for the tip mass M was set to 90 g so that the resonance frequency of the device in open-circuit approaches 100 Hz.

In order to obtain a more practical device design, the tip mass was modeled such that its volume would be minimal and well distributed. Hence, tungsten was chosen due to its high mass density and the tip mass is considered to be a prismatic bar along the plate width with square cross-section, as shown in Fig. 1. It is worthwhile to notice that the tip mass moment of inertia is also accounted for in the model.

The simulations performed in this work used a finite element model for laminated plates with piezoelectric layers connected to electric circuits described in Godoy and Trindade (2011). The model is based on an Equivalent Single Layer (ESL) formulation combined with First-order Shear Deformation Theory for which the layers may have independent electric degrees of freedom. Each piezoelectric layer may be connected to an independent electric circuit with resistance, inductance. The connection of circuits and patches considers that the electrodes entirely cover the patches surfaces resulting in an equipotential surface so that the electric charges

induced on the piezoelectric layers' electrodes are transferred to the electric circuit. The equipotential surface may also be composed of several patches. Considering the equivalence between electric charges in the patches and in the circuits to which they are connected, the following coupled equations of motion can be written (Godoy and Trindade, 2011):

$$\begin{bmatrix} \mathbf{M} & 0 \\ 0 & \mathbf{L}_c \end{bmatrix} \begin{Bmatrix} \ddot{\mathbf{u}} \\ \ddot{\mathbf{q}}_c \end{Bmatrix} + \begin{bmatrix} \mathbf{C} & 0 \\ 0 & \mathbf{R}_c \end{bmatrix} \begin{Bmatrix} \dot{\mathbf{u}} \\ \dot{\mathbf{q}}_c \end{Bmatrix} + \begin{bmatrix} \mathbf{K}_m & -\mathbf{K}_{me} \\ -\mathbf{K}_{me}^t & \mathbf{K}_e \end{bmatrix} \begin{Bmatrix} \mathbf{u} \\ \mathbf{q}_c \end{Bmatrix} = \begin{Bmatrix} \mathbf{F}_m \\ \mathbf{0} \end{Bmatrix}, \quad (1)$$

where \mathbf{K}_m , \mathbf{K}_{me} and \mathbf{K}_e are the mechanical, piezoelectric and dielectric stiffness matrices, respectively. \mathbf{M} and \mathbf{C} are the mass and damping matrices and \mathbf{F}_m is a vector of mechanical forces. \mathbf{L}_c and \mathbf{R}_c are diagonal matrices with the values of inductance and resistance of the shunt circuits.

The seismic mass was implemented in the model considering translational and rotational inertias at the free end of the cantilever plate and it was properly distributed in the corresponding finite element nodes. A transversal force located at the moving base (clamped end of the plate) was considered as excitation input. The transversal velocity at the same point is used as the measured mechanical output.

Mechanical and Electrical Frequency Responses Evaluation

In order to evaluate the mechanical and electrical frequency response functions of the structure with piezoelectric patches connected to a single electric shunt circuit, a harmonic mechanical excitation is considered, such that $\mathbf{F}_m = \mathbf{b}f$ and $f(t) = \tilde{f}e^{j\omega t}$, where \mathbf{b} is the vector of distribution of mechanical forces into the mechanical nodal degrees of freedom. Then, a point transversal velocity at the device base, $v(t) = \tilde{v}e^{j\omega t}$, is considered as the mechanical output and the electric current induced in the circuit, $I(t) = \tilde{I}e^{j\omega t}$, is considered as the electrical output. Thus, it is possible to define the frequency response functions from $\tilde{v} = G_{vF}(\omega)\tilde{f}$ (velocity output) and $\tilde{I} = G_{IF}(\omega)\tilde{f}$ (electric current output). A modal decomposition is considered for the nodal displacements such that $\mathbf{u} = \boldsymbol{\phi}\boldsymbol{\alpha}$, where $\boldsymbol{\phi}$ is the mass-normalized modal matrix and $\boldsymbol{\alpha}$ are the corresponding modal displacements. Hence, the modal displacements and circuit electric charges are written, respectively, as $\boldsymbol{\alpha} = \tilde{\boldsymbol{\alpha}}e^{j\omega t}$ and $\mathbf{q}_c = \tilde{\mathbf{q}}_ce^{j\omega t}$. Considering the assumptions above, the equations of motion (1) are rewritten as

$$(-\omega^2 \mathbf{I} + j2\omega \boldsymbol{\Lambda} \boldsymbol{\Omega} + \boldsymbol{\Omega}^2) \tilde{\boldsymbol{\alpha}} - \mathbf{K}_p \tilde{\mathbf{q}}_c = \mathbf{b}_\phi \tilde{f}, \quad (2)$$

$$(-\omega^2 L_c + j\omega R_c + K_e) \tilde{q}_c - \mathbf{K}_p^t \tilde{\boldsymbol{\alpha}} = 0, \quad (3)$$

where $\mathbf{K}_p = \boldsymbol{\phi}^t \mathbf{K}_{me}$ and $\mathbf{b}_\phi = \boldsymbol{\phi}^t \mathbf{b}$. $\boldsymbol{\Omega}$ is a diagonal matrix of squared eigenfrequencies for the structure with piezoelectric patches in open-circuit. $\boldsymbol{\Lambda}$ is a diagonal matrix of modal damping factors, thus it is supposed that the damping matrix \mathbf{C} is diagonalized by the undamped vibrations modes.

Solving (3) for \tilde{q}_c and substituting into (2), it is possible to write $\tilde{\boldsymbol{\alpha}}$ in terms of the excitation amplitude \tilde{f} . Then, the electric charge output due to the mechanical excitation can be solved substituting the obtained value of $\tilde{\boldsymbol{\alpha}}$ in (3).

The base (clamp) transversal velocity is written as $v = \mathbf{c}_v \dot{\mathbf{u}}$, where \mathbf{c}_v is a row vector that defines the nodal degree of freedom that is

measured. Thus, for the harmonic excitation $\tilde{v} = j\omega \mathbf{c}_\phi \tilde{\alpha}$ with $\mathbf{c}_\phi = \mathbf{c}_v \boldsymbol{\phi}$. Hence, the frequency response function of the velocity output due to a mechanical excitation is defined as $G_{vF} = \tilde{v}/\tilde{f}$, such that

$$G_{vF}(\omega) = j\omega(-\omega^2 L_c + j\omega R_c + K_e) \mathbf{c}_\phi [(-\omega^2 L_c + j\omega R_c + K_e) \times (-\omega^2 \mathbf{I} + j2\Lambda \boldsymbol{\Omega} \omega + \boldsymbol{\Omega}^2) - \mathbf{K}_p \mathbf{K}_p^t]^{-1} \mathbf{b}_\phi. \quad (4)$$

Notice that a resonant (RL) electric circuit may introduce an additional resonance frequency to the original structural resonance frequencies. These are coupled by the symmetric (but full) matrix $\mathbf{K}_p \mathbf{K}_p^t$ which relates to the effective modal piezoelectric coupling. The resonant electric circuit may also introduce an anti-resonance at the circuit resonance frequency.

The electric current output is obtained using $I = \dot{q}_c$ so that $\tilde{I} = j\omega \tilde{q}_c$ and the frequency response function $G_{IF} = \tilde{I}/\tilde{f}$ is written as

$$G_{IF}(\omega) = j\omega \mathbf{K}_p^t [(-\omega^2 L_c + j\omega R_c + K_e) \times (-\omega^2 + j2\Lambda \boldsymbol{\Omega} \omega + \boldsymbol{\Omega}^2) - \mathbf{K}_p \mathbf{K}_p^t]^{-1} \mathbf{b}_\phi. \quad (5)$$

By comparing equations (4) and (5), it is noticeable that, unlike the velocity frequency response G_{vF} , the electric current frequency response G_{IF} does not present the anti-resonance at the circuit resonance frequency.

It is also worthwhile to analyze the average harvesting performance over a given frequency-range. This was done here using the average of the amplitude of the electric current frequency response G_{IF} , defined as

$$|\bar{G}_{IF}| = \int_{\omega_t - \Delta\omega/2}^{\omega_t + \Delta\omega/2} |G_{IF}| d\omega, \quad (6)$$

where ω_t is the target harvesting frequency and $\Delta\omega$ is the frequency-range considered.

An alternative analysis of energy harvesting performance could be performed using the induced electric current per unit velocity at the point of force application. It is suggested here that this measure better represents the conversion of motion into electric current and, thus, could be a better measure of efficiency in energy harvesting. This can be defined as

$$G_{Iv}(\omega) = G_{IF}(\omega)/G_{vF}(\omega), \quad (7)$$

and thus may be evaluated by dividing equation (5) by equation (4).

To simplify the expressions above, consider the energy harvesting performance over a narrow frequency-range $\Delta\omega$ around the operating frequency ω_t to which the fundamental resonance frequency ω_n of the harvesting device was tuned. In this case, it is assumed that the structural response could be adequately represented by the first (fundamental) vibration mode. Thus, the nodal displacements are approximated as $\mathbf{u} \approx \boldsymbol{\phi}_n \alpha_n$ so that the frequency response function of base velocity per unit applied force G_{vF} can be rewritten as

$$G_{vF}(\omega) = j\omega c_n b_n (-\omega^2 L_c + j\omega R_c + K_e) [(-\omega^2 L_c + j\omega R_c + K_e) \times (-\omega^2 + j2\zeta_n \omega_n \omega + \omega_n^2) - K_p^2]^{-1}, \quad (8)$$

where $c_n = \mathbf{c}_v \boldsymbol{\phi}_n$ and $b_n = \boldsymbol{\phi}_n^t \mathbf{b}$ are the modal projections of the output and input distribution vectors, ζ_n is the structural modal damping factor for the fundamental vibration mode, and $K_p = \boldsymbol{\phi}_n^t \mathbf{K}_{me}$ represents the effective modal piezoelectric coupling coefficient. Notice that all parameters in (8) are scalars.

Similarly, the frequency response functions of circuit current output G_{IF} and G_{Iv} read

$$G_{IF}(\omega) = j\omega K_p b_n [(-\omega^2 L_c + j\omega R_c + K_e) \times (-\omega^2 + j2\zeta_n \omega_n \omega + \omega_n^2) - K_p^2]^{-1}, \quad (9)$$

$$G_{Iv}(\omega) = K_p c_n^{-1} (-\omega^2 L_c + j\omega R_c + K_e)^{-1}. \quad (10)$$

Electric Circuit Components Design

Two electric circuits were considered in this work. In both cases, the harvesting circuit (rectification and storage) is represented by constant electric impedance (resistance) supposing that the energy extracted (dissipated) from the plate by a resistive load could alternatively be stored in a real harvesting circuit. In the first case, only the equivalent resistive load is connected to the piezoelectric patches.

In the second case, an inductance is connected in series with the resistive load. The inductance provides an electrical resonance frequency to the circuit that may be tuned to the target operating frequency so that the circuit absorbs the energy from the structure when it vibrates with frequencies close to the target one.

In both cases, there may be optimal electric circuit parameters that maximize the amount of energy extracted from the structure. Although the values for the resistance, which represents the harvesting circuit, may be constrained by the harvesting circuit design, it is considered here that an optimal value for the resistance could be evaluated and then used as one of the design criteria for the harvesting circuit.

It was shown in previous studies on resistive shunted damping that a resistive circuit connected to a piezoelectric patch, bonded to a vibrating structure, acts like a viscoelastic material providing an effective loss factor that depends on the excitation frequency. The effective loss factor provided to the structure is maximized for the following resistance value (Trindade and Maio, 2008):

$$R_c = \frac{K_e \sqrt{1 - K_n^2}}{\omega_n}, \quad \text{with } K_n^2 = \frac{K_p^2}{K_e \omega_n^2}, \quad (11)$$

where K_e is the effective dielectric stiffness of the patches (inverse of their capacitance), ω_n is the fundamental resonance frequency, for the first bending vibration mode of the device with patches in open-circuit, and K_p is the modal piezoelectric coupling coefficient, projection of the electromechanical stiffness matrix onto the first bending vibration mode. K_n^2 is the effective squared modal electromechanical coupling coefficient which represents the ratio of energy converted by the piezoelectric material.

Substituting (11) into the frequency response expressions (8), (9) and (10) and after some algebraic manipulations and adimensionalization, these are rewritten as

$$G_{vF}(\omega) = j\omega \omega_n^{-2} c_n b_n (1 + j\delta \sqrt{1 - K_n^2}) \times [(1 + j\delta \sqrt{1 - K_n^2})(1 - \delta^2 + j2\zeta_n \delta) - K_n^2]^{-1}, \quad (12)$$

$$G_{IF}(\omega) = j\omega K_p^{-1} b_n K_n^2 \times [(1 + j\delta \sqrt{1 - K_n^2})(1 - \delta^2 + j2\zeta_n \delta) - K_n^2]^{-1}, \quad (13)$$

$$G_{Iv}(\omega) = K_p K_e^{-1} c_n^{-1} (1 + j\delta\sqrt{1 - K_n^2})^{-1}, \quad (14)$$

where the dimensionless frequency is defined as $\delta = \omega/\omega_n$.

In the case of resistive-inductive (resonant) circuit, techniques from the design of dynamic vibration absorbers can be used to design the circuit components in order to minimize the vibration amplitude of the structure. An optimum design would then indicate that an adequate amount of energy is being absorbed by the circuit and then dissipated (or harvested). There are a number of different techniques to design a dynamic vibration absorber but, in general terms, it is desired to design the circuit inertia (inductance) so that the circuit resonance frequency matches the operating frequency (or structural resonance frequency). Then, the resistance can be designed to provide the appropriate damping factor for the coupled resonances. The resistance and inductance that maximize the vibration amplitude reduction may be obtained using the formula (Godoy and Trindade, 2011)

$$L_c = \frac{K_e}{\omega_n^2}, \quad R_c = \frac{\sqrt{2}K_n K_e}{\omega_n}. \quad (15)$$

An alternative formulation for the design of shunt circuits can be found in Thomas, Deü and Ducarne (2009). Substituting Eq. (15) in Eqs. (8), (9) and (10) and with some algebraic manipulations, the frequency response functions are rewritten as

$$G_{vF}(\omega) = j\omega\omega_n^{-2}c_n b_n (1 - \delta^2 + j\delta\sqrt{2}K_n) \times \\ [(1 - \delta^2 + j\delta\sqrt{2}K_n)(1 - \delta^2 + j2\zeta_n\delta) - K_n^2]^{-1}, \quad (16)$$

$$G_{IF}(\omega) = j\omega b_n K_p^{-1} K_n^2 \times \\ [(1 - \delta^2 + j\delta\sqrt{2}K_n)(1 - \delta^2 + j2\zeta_n\delta) - K_n^2]^{-1}, \quad (17)$$

$$G_{Iv}(\omega) = K_p K_e^{-1} c_n^{-1} (1 - \delta^2 + j\delta\sqrt{2}K_n)^{-1}. \quad (18)$$

Notice that for $\delta = 1$, that is when the excitation frequency matches the natural frequency of the device, the frequency responses G_{vF} and G_{IF} are controlled by the structural damping ζ_n and the effective electromechanical coupling coefficient K_n , while the frequency response G_{Iv} is controlled only by K_n .

Energy Harvesting Performance Nominal Results

The performance of the energy harvesting device, shown in Fig. 1, was evaluated using the electric current frequency responses (5), (6) and (7) when subjected to a transversal force applied at the base (clamp). The two electric circuits, one purely resistive (R) and one resistive-inductive (RL), are considered and compared. Since the connection of the piezoelectric patches to the electric circuit (either R or RL) modifies the electric boundary condition (from the original open circuit condition), it is possible that the original tip mass does not guarantee a perfect tuning between operating and device resonance frequencies. The frequency response functions were evaluated using a reduced model obtained through projection onto a truncated modal basis composed of the first ten vibration modes.

Therefore, the value of the seismic mass was adjusted so that the resonance frequency, in the case of the resistive circuit, or the anti-resonance frequency, in the case of the resonant circuit, matches the target operating frequency ($\omega_t = 100$ Hz). For this purpose, the value of the seismic mass was empirically adjusted to each electric

boundary conditions leading to 88.5 g and 91 g for the R and RL circuits, respectively. For comparison purposes, the mass of the aluminum plate with the two piezoelectric patches is 9.4 g.

The electric circuit parameters were evaluated using (11) and (15) and then fine tuned manually, in the case of the resonant circuit. The optimal resistance for the resistive circuit was found to be $R_c = 13.3$ K Ω . For the resonant circuit, the resistance was found to be $R_c = 8.4$ K Ω and the inductance $L_c = 21.5$ H. Notice that this value of inductance is only attainable by using a synthetic inductance.

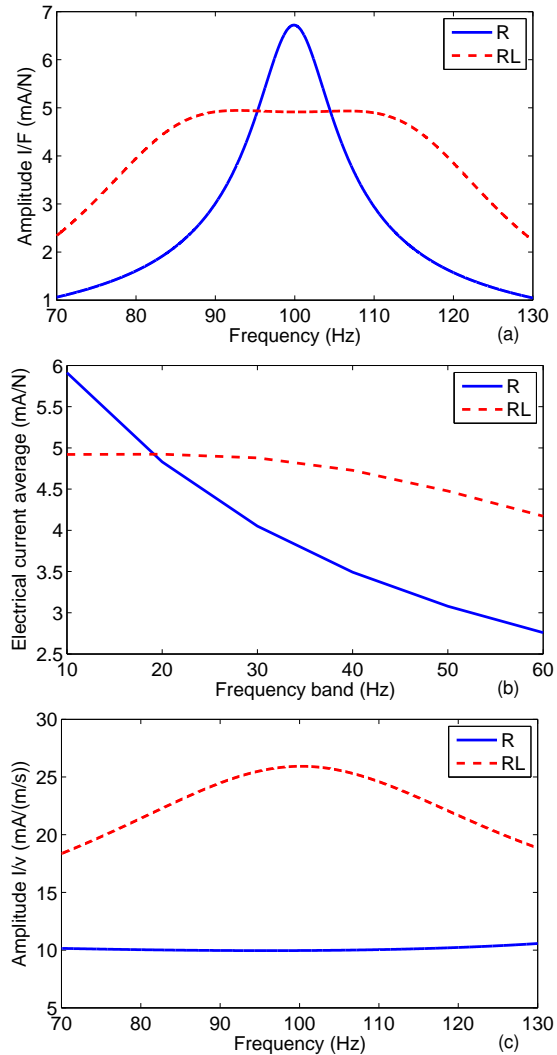


Figure 2. Nominal values for $G_{IF}(\omega)$ (a), $\bar{G}_{IF}(\Delta\omega)$ (b) and $G_{Iv}(\omega)$ (c) for resistive (R) and resonant (RL) circuits.

Figure 2a shows the nominal frequency response of the device, when excited by the transversal force, observed by the electric current induced in the circuit. It may be noted that at the peak frequency (100 Hz), the value obtained for the electric current per unit applied force is larger for the resistive circuit and, thus, does not justify the inclusion of the inductance. However, it may also be observed that the resonant circuit leads to a flatter performance level around the target frequency and, thus, may lead to a wider effective frequency range. Indeed, as shown in Fig. 2b, the average electric current induced in the circuit over a frequency range centered at the target frequency ω_t decreases rapidly for the resistive circuit, whereas it is almost constant up to a 30 Hz wide frequency range for the resonant circuit. Thus, the

average performance of the RL circuit is larger than the one of the R circuit for frequency ranges wider than 20 Hz. Therefore, this result indicates that in case of a variable or ill-known operating frequency or a mismatch between resonant and operating frequencies, the resonant circuit could yield a more robust performance.

It is well-known that a resonant circuit is generally more effective for reducing the structural vibration amplitude. Thus, it is reasonable to believe that, for a given applied transversal force, the input power is different for resistive and resonant circuits. Thus, an alternative analysis is performed for which the electric current induced in the circuit is evaluated per unit base velocity. It is suggested here that this could better represent the harvesting device effectiveness in terms of conversion of motion into electric current. Thus, Fig. 2c shows the amplitude of the frequency response of electric current per unit velocity G_{Iv} , according to Eq. (7). Note that, in this case, the resonant circuit is always more effective than the resistive one.

Given that the harvesting performance is very much dependent on a proper adjustment of the device geometric and material properties and circuit components, it is also worthwhile to analyze the effect of parametric uncertainties on the performance of harvesting devices using resistive and resonant circuits. Here, it is considered that the design of geometric properties should be sufficiently precise, whereas the piezoelectric material properties are generally not well-known and could be much less precise. In terms of circuit parameters, the inductance was found to have a much more important effect on the harvesting performance.

Stochastic Modeling for Uncertainty Quantification

This section presents an approach for analyzing uncertainties of piezoelectric material properties h_{31} and β_{33}^ξ and electric circuit inductance L_c . An appropriate probabilistic model for each random variable, denoted as X , is constructed accounting for the available information only, which is the following: (1) the support of the probability density function is $]0, +\infty[$; (2) the mean values are such that $E[X] = \bar{X}$; and (3) zero is a repulsive value for the positive-valued random variables, which is accounted for by the condition $E[\ln(X)] = c_X$ with $|c_X| < +\infty$. The Maximum Entropy Principle yields a Gamma probability density function for each stochastic variable X (Jaynes, 1957; Kapur, 1993; Soize, 2001; Ritto et al., 2010)

$$p_X(X) = \mathbb{I}_{]0, +\infty[} \left(\frac{1}{\delta_X^2 \bar{X}} \right)^{\delta_X^{-2}} \frac{X^{\delta_X^{-2}-1}}{\Gamma(\delta_X^{-2})} \exp\left(-\frac{X}{\delta_X^2 \bar{X}}\right), \quad (19)$$

in which $\delta_X = \sigma_X / \bar{X}$ is the relative dispersion of stochastic variable X and σ_X is its standard deviation ($X \in \{\widehat{h}_{31}, \widehat{\beta}_{33}^\xi, \widehat{L}_c\}$). The Gamma function is defined as $\Gamma(\alpha) = \int_0^\infty t^{\alpha-1} e^{-t} dt$.

Random realizations of the stochastic variables, $\{\widehat{h}_{31}(\theta_i), \widehat{\beta}_{33}^\xi(\theta_i), \widehat{L}_c(\theta_i)\}$, were then generated using MATLAB function *gamrnd*. Then, four analyses were performed. First, the effect of uncertainties on each individual stochastic variable was evaluated. Thus, for each realization of a given stochastic variable, the frequency response functions $\widehat{G}_{IF}(\omega)$ and $\widehat{G}_{Iv}(\omega)$ were evaluated. The average of the amplitude of \widehat{G}_{IF} for different frequency ranges, $\widehat{G}_{IF}(\Delta\omega)$, was also evaluated. This allows to analyze the individual effect of each stochastic variable. Then, the combined effect of all stochastic variables was evaluated. This was done by combining the vectors of realizations for each stochastic variable into a set $\{\widehat{h}_{31}(\theta_i), \widehat{\beta}_{33}^\xi(\theta_i), \widehat{L}_c(\theta_i)\}$ for which the same responses are evaluated ($\widehat{G}_{IF}(\theta_i, \omega)$, $\widehat{G}_{Iv}(\theta_i, \omega)$, $\widehat{G}_{IF}(\theta_i, \Delta\omega)$).

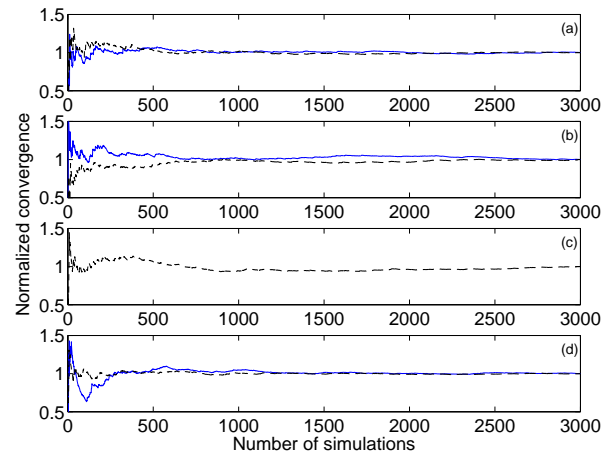


Figure 3. Mean square convergence for R (solid) and RL (dashed) circuits using as stochastic variables: (a) dielectric constant $\widehat{\beta}_{33}^\xi$, (b) piezoelectric constant \widehat{h}_{31} , (c) electric inductance \widehat{L}_c and (d) all three simultaneously.

For all three stochastic variables, a relative dispersion δ_X of 10% was considered. The mean-square convergence analysis with respect to the independent realizations of random variable $\widehat{G}_{IF}(\omega)$, denoted by $\widehat{G}_{IF}(\theta_j, \omega)$ was carried out considering the function

$$cov(n_s) = \frac{1}{n_s} \sum_{j=1}^{n_s} \int \|\widehat{G}_{IF}(\theta_j, \omega) - G_{IF}^N(\omega)\|^2 d\omega, \quad (20)$$

where n_s is the number of simulations and $G_{IF}^N(\omega)$ is the response calculated using the corresponding nominal model. Figure 3 shows the mean-square convergence analysis for the four cases considered. It is possible to observe that, for all cases, 1500 simulations seem to be enough to assure convergence.

The statistical analyses of the FRF amplitude outputs, $\widehat{G}_{IF}(\omega)$, $\widehat{G}_{Iv}(\omega)$, $\widehat{G}_{IF}(\Delta\omega)$, were performed using their 3000 realizations to calculate the corresponding mean values and 95% confidence intervals. The 95% confidence intervals were evaluated using the 2.5% and 97.5% percentiles of the realizations of $\widehat{G}_{IF}(\theta_i, \omega)$ and $\widehat{G}_{Iv}(\theta_i, \omega)$ frequency response amplitudes at each frequency and of $\widehat{G}_{IF}(\theta_i, \Delta\omega)$ for each frequency-range $\Delta\omega$ considered.

Uncertainty Quantification Results

This section presents the uncertainty quantification results for each one of the four cases considered. For that, the mean values and confidence intervals for $\widehat{G}_{IF}(\omega)$, $\widehat{G}_{Iv}(\omega)$ and $\widehat{G}_{IF}(\Delta\omega)$ are analyzed. The main purpose of such analyses are to evaluate the effect of parametric uncertainties on the energy harvesting performance of standard (resistive or R) and resonant (RL) circuits.

First, the effect of dielectric constant β_{33}^ξ is analyzed. The main motivation for such analysis is that, in general, only free β_{33}^σ or blocked β_{33}^ξ dielectric constants are provided by manufacturers and thus considered in modeling piezoelectric structures. However, for piezoelectric patches bonded to or embedded in host structures, neither constant represents the actual mechanical boundary conditions of the piezoelectric patch. Thus, the effective dielectric constant is generally unknown and must be approximated by measurement of bonded patch static capacitance. The dielectric constant may have three major effects on the energy harvesting performance. First, it affects the amount of charge induced in the patches electrodes for

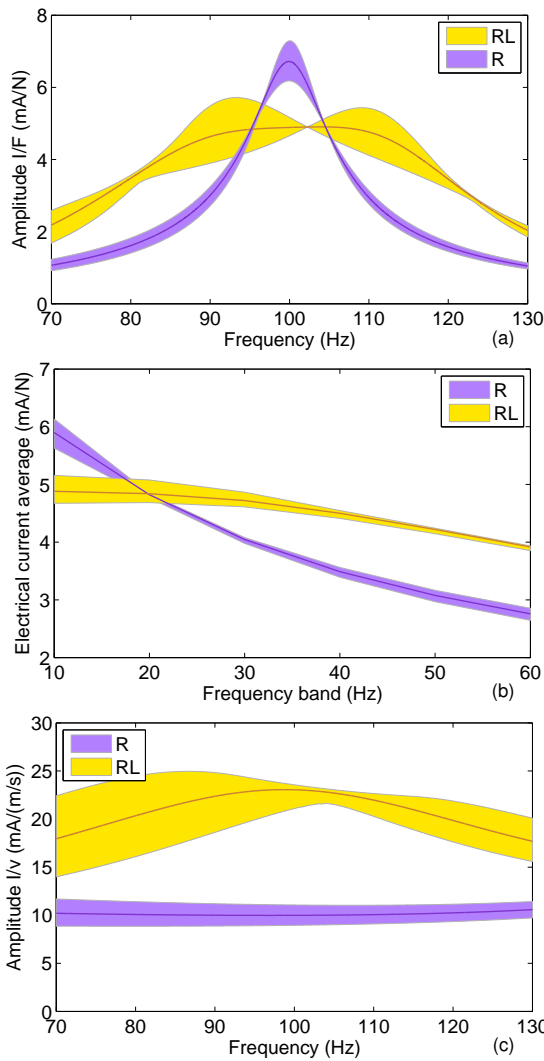


Figure 4. Mean values (solid) and confidence intervals (filled) for $\widehat{G}_{IF}(\omega)$ (a), $\widehat{G}_{IF}(\Delta\omega)$ (b) and $\widehat{G}_{Iv}(\omega)$ (c) for resistive (R) and resonant (RL) circuits and uncertain dielectric constant β_{33}^{ϵ} .

a given patch deformation. Second, it affects the effective structural stiffness and, thus, resonance frequencies. Third, for a resonant circuit (RL), it affects the circuit resonance frequency and, thus, the proper tuning between circuit resonance frequency and target harvesting frequency.

Figure 4 shows the mean values and 95% confidence intervals for $\widehat{G}_{IF}(\omega)$, $\widehat{G}_{IF}(\Delta\omega)$ and $\widehat{G}_{Iv}(\omega)$ for resistive (R) and resonant (RL) circuits. It can be noticed that, as expected, the performance of the resistive circuit is much less dependent on the dielectric constant and, thus, its corresponding confidence intervals are narrower. In a worst case scenario, the dielectric constant may reduce the energy harvesting performance of a resonant circuit by detuning the device (Fig. 4a). However, the efficiency of the resonant circuit is always superior to the resistive one (Fig. 4c), although more dependent on the dielectric constant and, thus, less robust. On the other hand, the average performance over a frequency-range is less sensitive to the dielectric constant and for all frequency-ranges considered, the resonant circuit seems to be more interesting since it widens the effective harvesting frequency-range of the device (Fig. 4b).

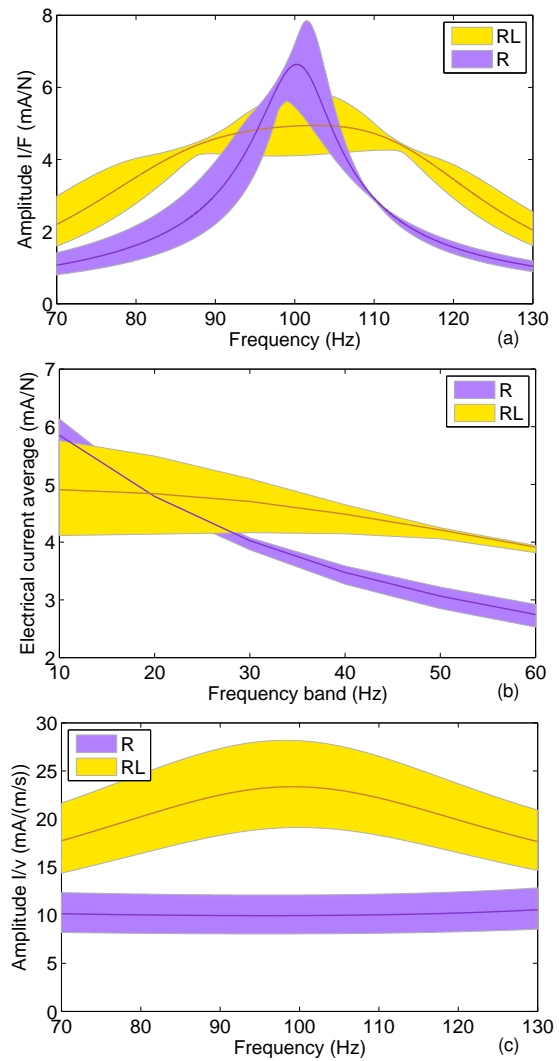


Figure 5. Mean values (solid) and confidence intervals (filled) for $\widehat{G}_{IF}(\omega)$ (a), $\widehat{G}_{IF}(\Delta\omega)$ (b) and $\widehat{G}_{Iv}(\omega)$ (c) for resistive (R) and resonant (RL) circuits and uncertain piezoelectric constant h_{31} .

In a second analysis, the effect of uncertainties of piezoelectric constant h_{31} on the energy harvesting performance is analyzed. It is expected that, for both resistive and resonant circuits, the higher the piezoelectric constant the better, since this constant affects directly the amount of mechanical energy converted into electrical energy and, thus, potentially harvested. Thus, in opposition to the previous case, the piezoelectric constant does not detune the device, but instead amplifies (or reduces) the amount of energy potentially harvested.

Figure 5 shows the effect of uncertain piezoelectric constant h_{31} on the energy harvesting performance through mean values and confidence intervals for $\widehat{G}_{IF}(\omega)$, $\widehat{G}_{IF}(\Delta\omega)$ and $\widehat{G}_{Iv}(\omega)$ for resistive (R) and resonant (RL) circuits. One may notice that the confidence intervals for the resistive circuit are wider than in the previous case. In the case of resonant circuit, the harvesting performance confidence interval is very wide at the target frequency (100 Hz) as shown in Fig. 5a, although it shrinks significantly over increasing frequency-ranges (Fig. 5b). As in the previous case, the device efficiency is always superior for a resonant circuit (Fig. 5c).

For the third analysis, the inductance of the resonant circuit is

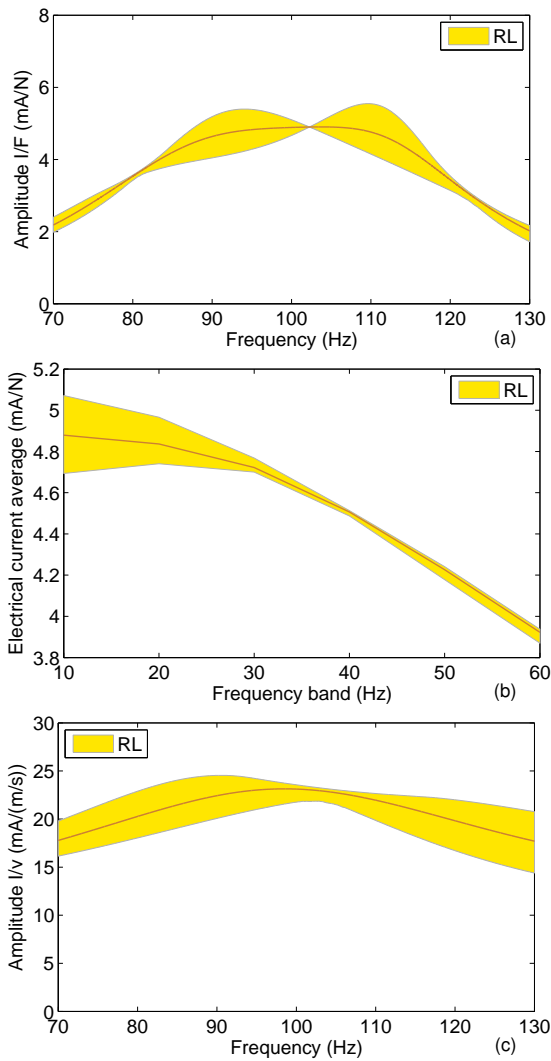


Figure 6. Mean values (solid) and confidence intervals (filled) for $\widehat{G}_{IF}(\omega)$ (a), $\widehat{G}_{IF}(\Delta\omega)$ (b) and $\widehat{G}_{Iv}(\omega)$ (c) for resonant circuit and uncertain circuit inductance \widehat{L}_c .

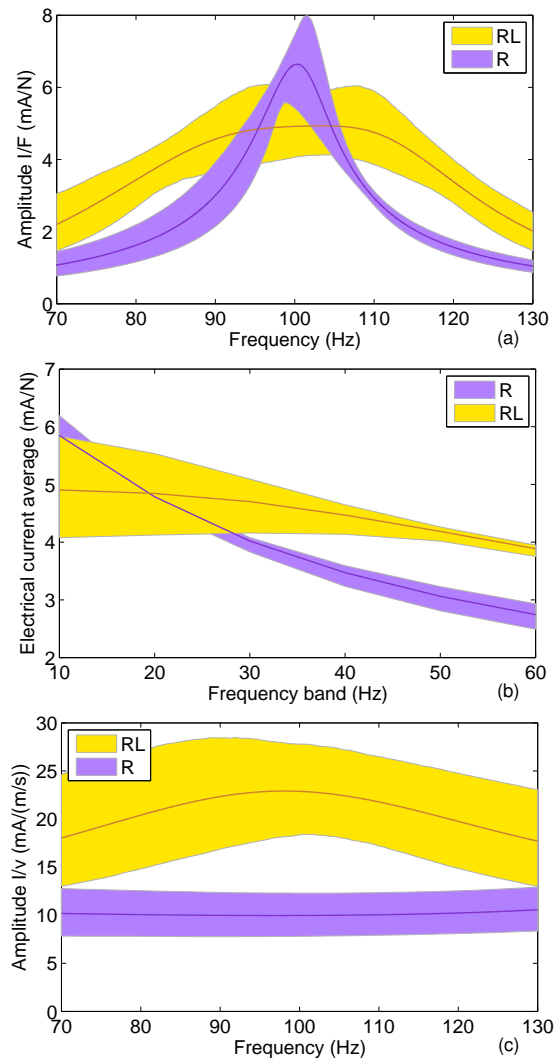


Figure 7. Mean values (solid) and confidence intervals (filled) for $\widehat{G}_{IF}(\omega)$ (a), $\widehat{G}_{IF}(\Delta\omega)$ (b) and $\widehat{G}_{Iv}(\omega)$ (c) for resistive (R) and resonant (RL) circuits and uncertain parameters $\widehat{\beta}_{33}^\varepsilon$, \widehat{h}_{31} and \widehat{L}_c .

considered as uncertain, consequently only the resonant circuit device is analyzed. This analysis is motivated by the fact that, in practice, synthetic inductance circuits should be used to attain the very high inductance values required. These circuits are composed of a number of electronic components which are subjected to uncertainties and/or variabilities. Figure 6 shows the mean values and 95% confidence intervals for $\widehat{G}_{IF}(\omega)$, $\widehat{G}_{IF}(\Delta\omega)$ and $\widehat{G}_{Iv}(\omega)$. As expected, the main effect of circuit inductance uncertainties is to detune the device, although dispersion of \widehat{G}_{IF} is almost negligible for a frequency near the target one (around 101 Hz), as shown in Fig. 6a. This frequency could be designed to match the target one in order to obtain a harvesting performance robust to uncertainties of the circuit inductance. On the other hand, the detuning does not significantly affects the average harvesting performance (Fig. 6b).

Finally, an analysis of the effect of simultaneous uncertainties of the previous three parameters on the energy harvesting performance is performed. In this case, the realizations of dielectric constant $\widehat{\beta}_{33}^\varepsilon$, piezoelectric constant \widehat{h}_{31} and circuit inductance \widehat{L}_c were combined to evaluate the mean values and 95% confidence intervals of $\widehat{G}_{IF}(\omega)$,

$\widehat{G}_{IF}(\Delta\omega)$ and $\widehat{G}_{Iv}(\omega)$. The results are shown in Fig. 7. As expected from the previous analyses, the confidence intervals for the resonant circuit are wider than those for the resistive circuit. The predicted harvesting performance for resistive and resonant circuits at the target frequency is the same when measured by \widehat{G}_{IF} (Fig. 7a), however the performance of the resonant circuit device is superior when considering average performance over a wider frequency-range (Fig. 7b). In terms of efficiency, the resonant circuit device is also always superior to the resistive one (Fig. 7c).

Previous results were obtained considering a 10% dispersion for the stochastic variables. It is worthwhile to notice that neither the stochastic model (Gamma probability density function) nor its parameters (mean and dispersion) were validated since no real measurements were available for the three parameters considered. While it is quite reasonable to consider the data provided by the manufacturer (for β_{33}^ε and h_{31}) and design value (for L_c) as nominal (mean) values, the dispersion of these variables can only be guessed. Therefore, a parametric analysis of the parameters dispersions was also performed. For the sake of brevity, only results for the electric current average over a 10 Hz frequency band are presented. Its mean

values and confidence intervals for various parameters dispersions are shown in Fig. 8. Notice that the mean values of the electric current average do not change substantially for increasing parameters dispersions. On the other hand, as expected, higher parameters dispersions yield wider confidence intervals. Comparison of Figs. 8a, 8b and 8c shows that the electric current average confidence intervals are more sensitive to increases in the dispersion of piezoelectric material constant h_{31} .

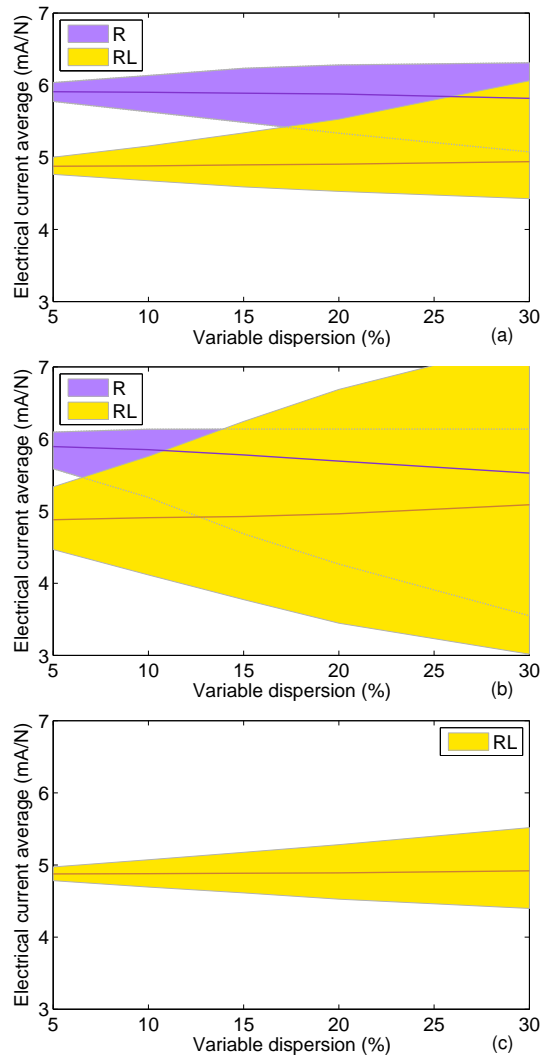


Figure 8. Confidence interval of the electric current average over a 10 Hz frequency band for several parameters dispersions. a) β_{33} , b) h_{31} and c) L_c .

Conclusions

The effect of parametric uncertainties on the performance of a piezoelectric energy harvesting device was analyzed. A cantilever plate with bonded piezoelectric patches and a tip-mass serves as the energy harvesting device. Piezoelectric and dielectric constants of active layers and inductance of electric circuit were considered as stochastic parameters. Mean and confidence intervals of the electric output were evaluated. Results have shown that, for 10% dispersion on the three parameters considered, the predicted harvesting performance for resistive circuits at the target frequency is more important than the one for resonant circuits, when measured

by G_{IF} ; however, the performance of the resonant circuit device is superior when considering average performance over a wider frequency-range \bar{G}_{IF} . In terms of efficiency, measured by electric current induced in the circuit per unit base velocity G_{IV} , the resonant circuit device is always superior to the resistive one. All parameters considered as stochastic are relevant to the harvesting performance confidence intervals. For the resonant circuit, the dielectric material constant and electric circuit inductance affect mainly the proper tuning between resonance and operating frequency, while the piezoelectric material constant leads only to amplification/reduction of the harvesting performance.

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